



100V N-Channel Enhancement Mode MOSFET

Voltage

100 V

Current

13A

Features

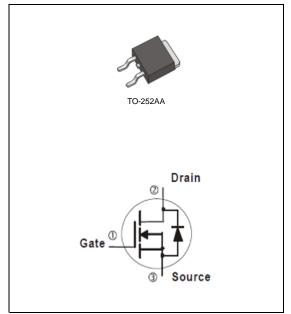
- RDS(ON), VGS@10V, ID@6.5A<115mΩ
- RDS(ON), VGS@4.5V, ID@4A<120mΩ
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std.. (Halogen Free)

Mechanical Data

• Case: TO-252AA Package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0104 ounces, 0.297 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS | |
|--|-----------------------|-----------------|-------------|-------|--|
| Drain-Source Voltage | | V_{DS} | 100 | V | |
| Gate-Source Voltage | | V_{GS} | <u>+</u> 20 | V | |
| Continuous Drain Current | T _C =25°C | l _D | 13 | А | |
| | T _C =100°C | | 8 | | |
| Pulsed Drain Current (Note 1) | T _C =25°C | I _{DM} | 52 | | |
| Power Dissipation | T _C =25°C | Po | 41 | 10/ | |
| | T _C =100°C | | 16 | W | |
| Continuous Drain Current | T _A =25°C | I _D | 2.9 | Α | |
| | T _A =70°C | | 2.3 | Α | |
| Power Dissipation | T _A =25°C | 7 | 2.0 | W | |
| | T _A =70°C | Pb | 1.3 | | |
| Single Pulse Avalanche Energy (Note 6) | | E _{AS} | 6.1 | mJ | |
| Operating Junction and Storage Temperature Range | | T_J, T_{STG} | -55~150 | °C | |
| Typical Thermal Resistance (Note 4,5) | Junction to Case | $R_{	heta JC}$ | 3.05 | °C/W | |
| | Junction to Ambient | $R_{\theta JA}$ | 62.5 | | |

• Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|----------------------------------|---------------------|---|------|------|--------------|-------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | V _{GS} =0V,I _D =250uA | 100 | - | - | V |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}$, $I_{D}=250uA$ | 1.0 | 1.76 | 2.5 | V |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =10V,I _D =6.5A | - | 92 | 115 | mΩ |
| | | V _{GS} =4.5V,I _D =4A | - | 95 | 120 | |
| Zero Gate Voltage Drain Current | I_{DSS} | V _{DS} =100V,V _{GS} =0V | - | - | 1.0 | uA |
| Gate-Source Leakage Current | I_{GSS} | V _{GS} = <u>+</u> 20V,V _{DS} =0V | 1 | - | <u>+</u> 100 | nA |
| Dynamic (Note 7) | | | | | | |
| Total Gate Charge | Q_{g} | V _{DS} =50V, I _D =2A, V _{GS} =10V ^(Note 1,2) | - | 20 | - | nC |
| Gate-Source Charge | Q_gs | | - | 3.2 | - | |
| Gate-Drain Charge | Q_{gd} | | - | 3.6 | - | |
| Input Capacitance | Ciss | V _{DS} =25V, V _{GS} =0V, f=1.0MHZ | - | 1413 | - | pF |
| Output Capacitance | Coss | | - | 60 | - | |
| Reverse Transfer Capacitance | Crss | | - | 34 | - | |
| Turn-On Delay Time | td _(on) | V_{DD} =50V, I_{D} =1A, V_{GS} =10V, R_{G} =3.3 Ω (Note 1,2) | - | 18 | - | |
| Turn-On Rise Time | t _r | | - | 4.3 | - | ns |
| Turn-Off Delay Time | td _(off) | | - | 41 | - | |
| Turn-Off Fall Time | t _f | | 1 | 4.2 | - | |
| Drain-Source Diode | | | | | | |
| Maximum Continuous Drain-Source | | | - | - | 13 | А |
| Diode Forward Current | I _S | | | | | |
| Diode Forward Voltage | V_{SD} | I _S =1A,V _{GS} =0V | - | 0.73 | 1 | V |

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited.
- 5. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I_{AS} =11A, V_{DD} =25V, V_{GS} =10V
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

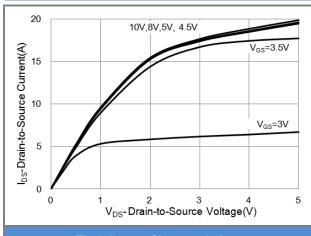


Fig.1 Output Characteristics

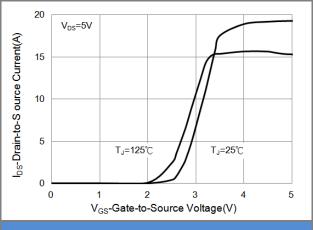


Fig.2 Transfer Characteristics

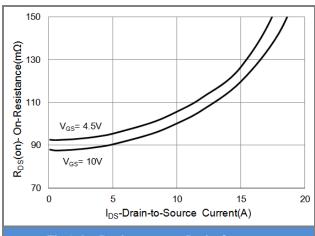


Fig.3 On-Resistance vs. Drain Current

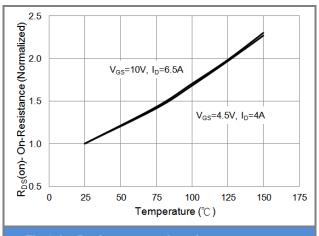
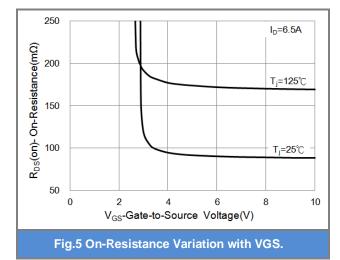
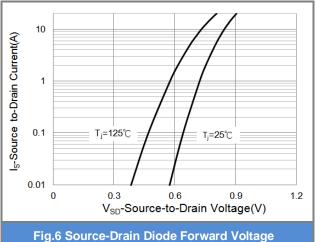


Fig.4 On-Resistance vs. Junction temperature









TYPICAL CHARACTERISTIC CURVES

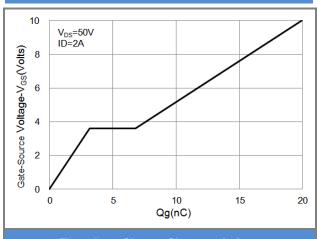


Fig.7 Gate-Charge Characteristics

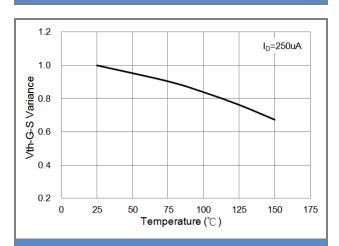
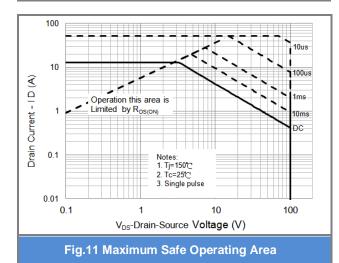


Fig.9 Threshold Voltage Variation with Temperature



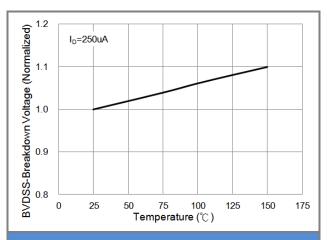


Fig.8 Breakdown Voltage Variation vs. Temperature

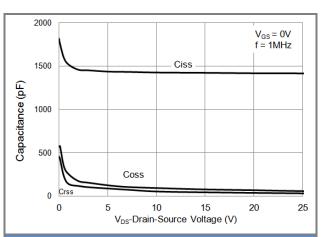


Fig.10 Capacitance vs. Drain-Source Voltage





TYPICAL CHARACTERISTIC CURVES

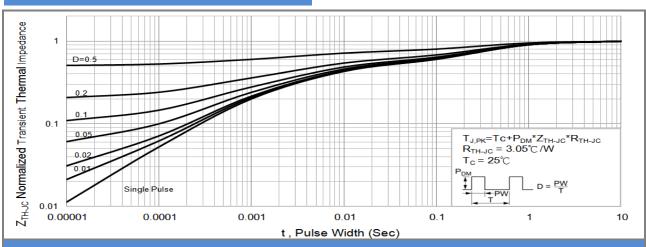
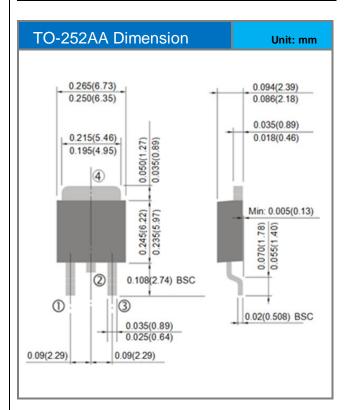


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width





Packaging Information



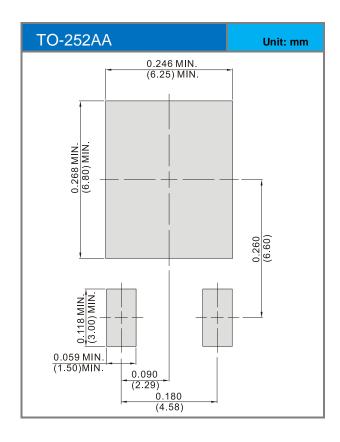




PART NO PACKING CODE VERSION

| Part No Packing Code | Package Type | Packing Type | Marking | Version | |
|----------------------|--------------|---------------------|---------|--------------|--|
| PJD13N10A_L2_00001 | TO-252AA | 3,000pcs / 13" reel | D13N10A | Halogen free | |

MOUNTING PAD LAYOUT







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